



DXT5551P5

160V NPN HIGH VOLTAGE TRANSISTOR
PowerDI®5

Features and Benefits

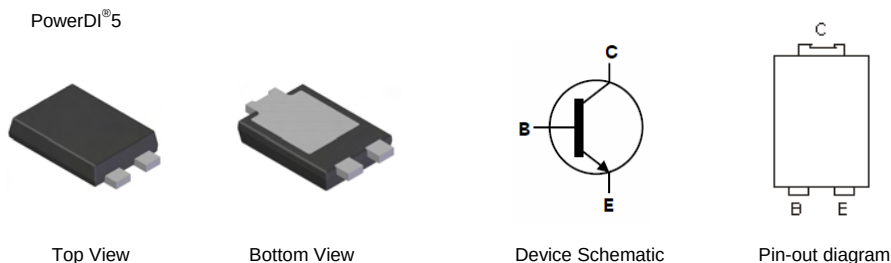
- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 2.25W
- $BV_{CEO} > 160V$
- $I_{C(cont)} = 0.6A$
- **Lead Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free, "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Applications

- Telecom line driver

Mechanical Data

- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin annealed over Copper leadframe.
Solderable per MIL-STD-202, Method 208 Ⓔ3
- Weight: 0.093 grams (approximate)

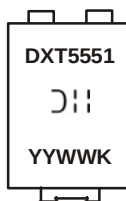


Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT5551P5-13	DXT5551	13	16	5,000

- Notes:
1. No purposefully added lead.
 2. Halogen and Antimony Free. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



DXT5551 = Product Type Marking Code
 J|| = Manufacturers' Code Marking
 K = Factory Designator
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 09 for 2009)
 WW = Week code (01 - 53)

Maximum Ratings @T_A = 25°C unless otherwise specified

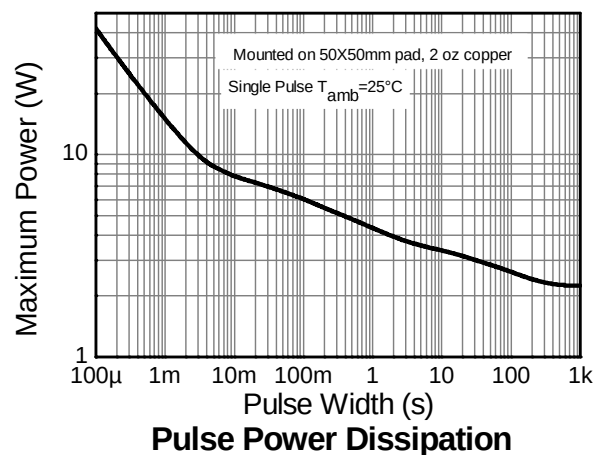
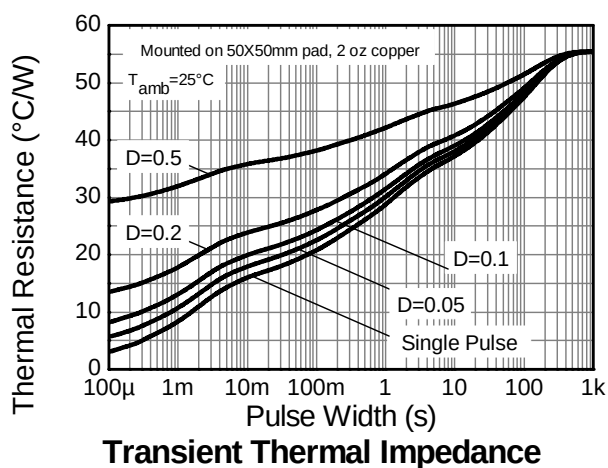
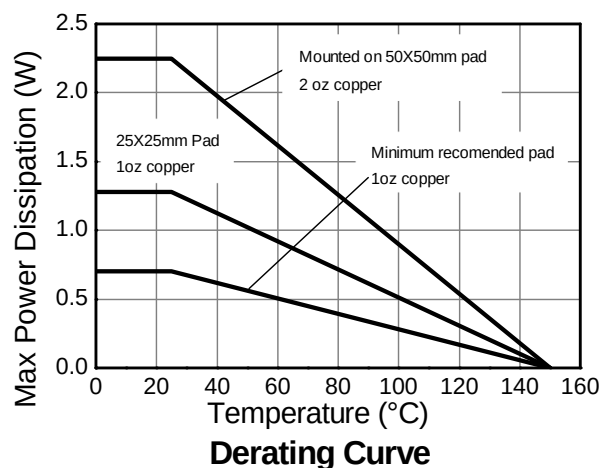
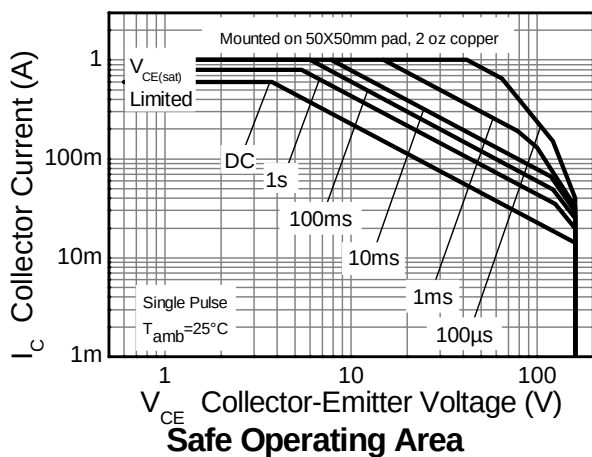
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6	V
Continuous Collector Current	I _C	600	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _D	2.25	W
Thermal Resistance, Junction to Ambient Air (Note 4)	R _{θJA}	55.5	°C/W
Power Dissipation (Note 5)	P _D	1.28	W
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	97.4	°C/W
Power Dissipation (Note 6)	P _D	0.7	W
Thermal Resistance, Junction to Ambient Air (Note 6)	R _{θJA}	179	°C/W
Thermal Resistance, Junction to Collector Terminal	R _{θJT}	30	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 4. Device mounted on 1.6mm FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
5. Device mounted on 1.6mm FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
6. Device mounted on 1.6mm FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.

Thermal Characteristics

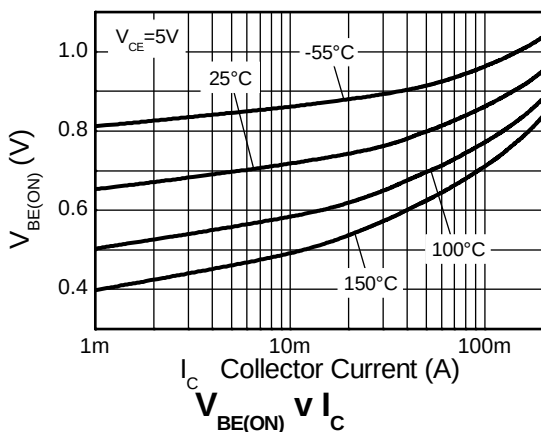
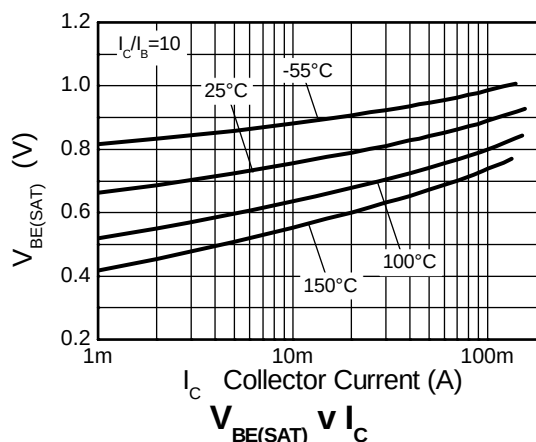
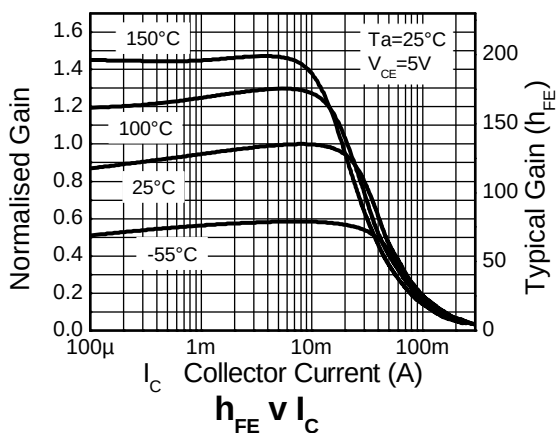
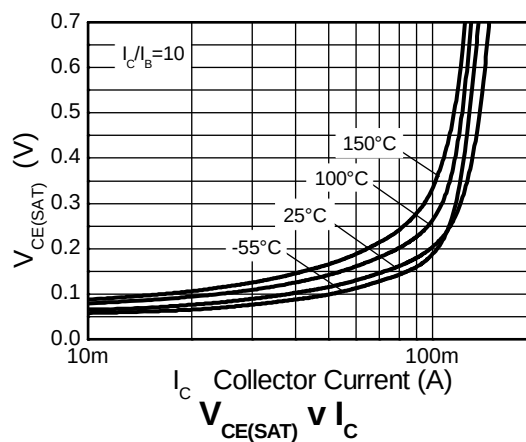
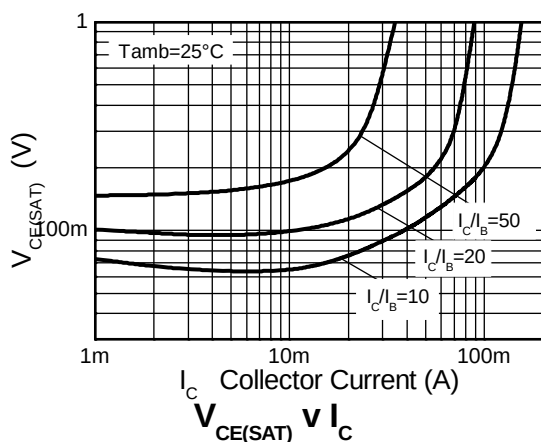


Electrical Characteristics @T_A = 25°C unless otherwise specified

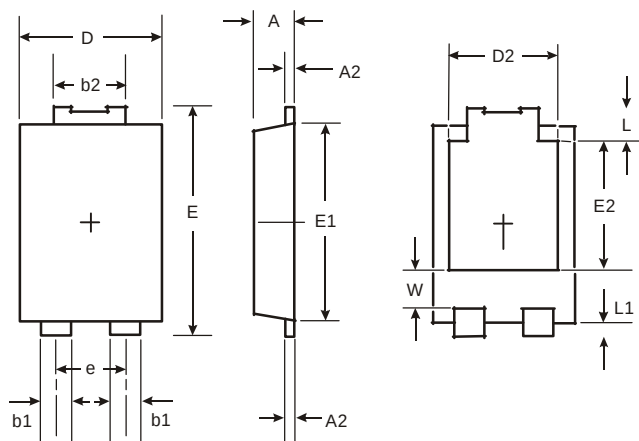
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	180	270	–	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	160	200	–	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	7.85	–	V	I _E = 10μA
Collector Cutoff Current	I _{CBO}	–	<1	50	nA	V _{CB} = 120V
		–	–	50	μA	V _{CB} = 120V, T _A = 100°C
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	–	65	150	mV	I _C = 10mA, I _B = 1mA
		–	115	200	mV	I _C = 50mA, I _B = 5mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	–	760	1000	mV	I _C = 10mA, I _B = 1mA
		–	840	1200	mV	I _C = 50mA, I _B = 5mA
DC Current Gain (Note 7)	h _{FE}	80	130	–	–	V _{CE} = 5V, I _C = 1mA
		80	145	250	–	V _{CE} = 5V, I _C = 10mA
		30	65	–	–	V _{CE} = 5V, I _C = 50mA
Transition Frequency	f _T	–	130	–	MHz	V _{CE} = 10V, I _C = 10mA, f = 100MHz
Output Capacitance (Note 7)	C _{obo}	–	–	6	pF	V _{CB} = 10V, f = 1MHz
Delay Time	t _d	–	95	–	ns	V _{CC} = 510V, I _C = 10mA, I _{B1} = I _{B2} = 1mA
Rise Time	t _r	–	64	–	ns	
Storage Time	t _s	–	1256	–	ns	
Delay Time	t _f	–	140	–	ns	

Notes: 7. Pulse Test: Pulse width ≤300μs. Duty cycle ≤2.0%.

Typical Characteristics

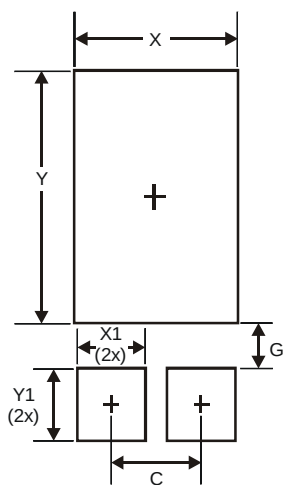


Package Outline Dimensions



PowerDI [®] 5		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.054 Typ	
E	6.40	6.60
e	1.84 Typ	
E1	5.30	5.45
E2	3.549 Typ	
L	0.75	0.95
L1	0.50	0.65
W	1.10	1.41
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
C	1.840
G	0.852
X	3.360
X1	1.390
Y	4.860
Y1	1.400

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9